

3 Hours

Max Marks: 80

N.B.

- 1) Q. No. 1 is compulsory.
 - 2) Attempt any three out of remaining questions.
 - 3) Assume any suitable data wherever required but justify the same.
- 1 a Give few examples of MEMS device which are characterized by sensors and actuators. 20
 - b Explain the sacrificial layer and its role in fabrication of MEMS devices
 - c What are the characteristics of Micro-heater?
 - d In case of photolithography, Compare the two types of photo-resist used
 - 2 a Discuss the process of photolithography. Mention the types of photolithography suitable for at least two MEMS devices with justification. 10
 - b Discuss selection of material based on applications. Support your answer by considering suitable example. 10
 - 3 a A 30 μm thick membrane is needed for a pressure sensor application. Calculate the size of the mask opening W needed for the V groove if the full wafer thickness is 600 μm using an-isotropic ($\text{Tan } 54.74^\circ$) etching below the silicon $\langle 100 \rangle$ surface. 10
 - b Explain Dry etching & Wet etching in fabrication process of MEMS devices. 10
 - 4 a Describe the representative process flow for fabricating the ink jet printer head by Hewlett-Packard. Also explain the operating principle of this MEMS device in detail. 10
 - b Differentiate between bulk and surface micromachining for fabrication of MEMS devices with suitable example 10
 - 5 a State various Chemical Vapor Deposition Techniques. Explain in brief the techniques of Chemical Vapor Deposition for MEMS device fabrication. 10
 - b Explain transduction pertaining to microfilm strain gauge. State the factors that lead to thin film stress 10
 - 6 Write a short note on (any three) 20
 - a Photolithography(Compare major types of exposure system)
 - b Anodic bonding
 - c Reliability of MEMS devices.
 - d Applications of MEMS in Biomedical Instrumentation
-